

November 1992 Revised January 1999

74ABT652

Octal Transceivers and Registers with 3-STATE Outputs

General Description

The ABT652 consists of bus transceiver circuits with D-type flip-flops and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to HIGH logic level. Output Enable pins (OEAB, \overline{OEBA}) are provided to control the transceiver function.

Features

- Independent registers for A and B buses
- Multiplexed real-time and stored data

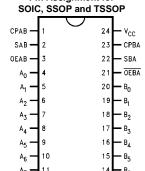
- A and B output sink capability of 64 mA, source capability of 32 mA
- Guaranteed output skew
- Guaranteed multiple output switching specifications
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability

Ordering Code:

Order Number	Package Number	Package Description
74ABT652CSC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Body
74ABT652CMSA	MSA24	24-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74ABT652CMTC	MTC24	24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Pin Assignment for

Pin Descriptions

Pin Names	Description
A ₀ -A ₇	Data Register A Inputs/3-STATE Outputs
B ₀ -B ₇	Data Register B Inputs/3-STATE Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Select Inputs
OEAB, $\overline{\text{OEBA}}$	Output Enable Inputs

GND - 12

Truth Table

		Inp	uts			Inputs/Outp	outs (Note 1)	Operating Mode
OEAB	OEBA	CPAB	СРВА	SAB	SBA	A ₀ thru A ₇	B ₀ thru B ₇	
L	Н	H or L	H or L	X	Х	Input	Input	Isolation
L	Н	\	\	Х	Х			Store A and B Data
Х	Н	\	H or L	Х	Х	Input	Not Specified	Store A, Hold B
Н	Н	\	\	Х	Х	Input	Output	Store A in Both Registers
L	Х	H or L	\	Х	Х	Not Specified	Input	Hold A, Store B
L	L	\		Х	Х	Output	Input	Store B in Both Registers
L	L	Х	Х	Х	L	Output	Input	Real-Time B Data to A Bus
L	L	Х	H or L	Х	Н			Store B Data to A Bus
Н	Н	Х	Х	L	Х	Input	Output	Real-Time A Data to B Bus
Н	Н	H or L	Х	Н	Х			Stored A Data to B Bus
Н	L	H or L	H or L	Н	Н	Output	Output	Stored A Data to B Bus and
								Stored B Data to A Bus

H = HIGH Voltage Level

Note 1: The data output functions may be enabled or disabled by various signals at OEAB or OEBA inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW to HIGH transition on the clock inputs.

Functional Description

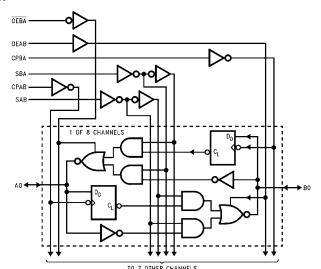
In the transceiver mode, data present at the HIGH impedance port may be stored in either the A or B register or both

The select (SAB, SBA) controls can multiplex stored and real-time.

The examples in Figure 1 demonstrate the four fundamental bus-management functions that can be performed with the ABT652.

Data on the A or B data bus, or both, can be stored in the internal D flip-flop by LOW to HIGH transitions at the appropriate Clock Inputs (CPAB, CPBA) regardless of the Select or Output Enable Inputs. When SAB and SBA are in the real time transfer mode, it is also possible to store data without using the internal D flip-flops by simultaneously enabling OEAB and OEBA. In this configuration each Output reinforces its Input. Thus when all other data sources to the two sets of bus lines are in a HIGH impedance state, each set of bus lines will remain at its last state.

Logic Diagram

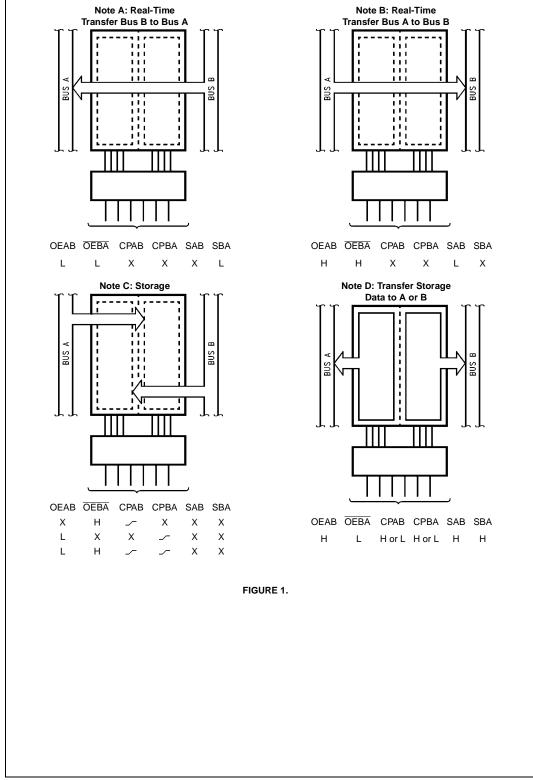


TO 7 OTHER CHANNELS

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

L = LOW Voltage Level

X = Immaterial



Absolute Maximum Ratings(Note 2)

Over Voltage Latchup (I/O)

10V

Voltage Applied to Any Output

in the Disable

or Power-Off State -0.5 V to +5.5 V in the HIGH State $-0.5 \text{V to } \text{V}_{\text{CC}}$

Current Applied to Output

in LOW State (Max) twice the rated I_{OL} (mA) DC Latchup Source Current -500 mA

Recommended Operating Conditions

Free Air Ambient Temperature $-40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$ Supply Voltage +4.5V to +5.5V

Minimum Input Edge Rate (ΔV/Δt)

 Data Input
 50 mV/ns

 Enable Input
 20 mV/ns

 Clock Input
 100 mV/ns

Note 2: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation

under these conditions is not implied.

Note 3: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter	Min	Тур	Max	Units	V _{CC}	Conditions
V _{IH}	Input HIGH Voltage	2.0			V		Recognized HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA (Non I/O Pins)
V _{OH}	Output HIGH	2.5			V	Min	$I_{OH} = -3 \text{ mA}, (A_n, B_n)$
	Voltage	2.0					$I_{OH} = -32 \text{ mA}, (A_n, B_n)$
V _{OL}	Output LOW Voltage			0.55	V	Min	$I_{OL} = 64 \text{ mA}, (A_n, B_n)$
V _{ID}	Input Leakage Test	4.75			V	0.0	$I_{ID} = 1.9 \mu A$, (Non-I/O Pins)
							All Other Pins Grounded
I _{IH}	Input HIGH Current			1	μΑ	Max	V _{IN} = 2.7V (Non-I/O Pins) (Note 4)
				1			$V_{IN} = V_{CC}$ (Non-I/O Pins)
I _{BVI}	Input HIGH Current Breakdown Test			7	μΑ	Max	V _{IN} = 7.0V (Non-I/O Pins)
I _{BVIT}	Input HIGH Current Breakdown Test (I/O)			100	μΑ	Max	$V_{IN} = 5.5V (A_n, B_n)$
I _{IL}	Input LOW Current			-1	μΑ	Max	V _{IN} = 0.5V (Non-I/O Pins) (Note 4)
				-1			V _{IN} = 0.0V (Non-I/O Pins)
I _{IH} +	Output Leakage Current			10	μА	0V-5.5V	$V_{OUT} = 2.7V (A_n, B_n);$
l _{OZH}							OEBA = 2.0V and OEAB = GND = 2.0V
I _{IL} + I _{OZL}	Output Leakage Current			-10	μΑ	0V-5.5V	$V_{OUT} = 0.5V (A_n, B_n);$
							$\overline{\text{OEBA}}$ = 2.0V and OEAB = GND = 2.0V
Ios	Output Short-Circuit Current	-100		-275	mA	Max	$V_{OUT} = 0V (A_n, B_n)$
I _{CEX}	Output HIGH Leakage Current			50	μΑ	Max	$V_{OUT} = V_{CC} (A_n, B_n)$
I _{ZZ}	Bus Drainage Test			100	μΑ	0.0V	V _{OUT} = 5.5V (A _n , B _n); All Others GND
I _{CCH}	Power Supply Current			250	μΑ	Max	All Outputs HIGH
I _{CCL}	Power Supply Current			30	mA	Max	All Outputs LOW
I _{CCZ}	Power Supply Current			50	μΑ	Max	Outputs 3-STATE;
							All others at V _{CC} or GND
I _{CCT}	Additional I _{CC} /Input			2.5	mA	Max	$V_I = V_{CC} - 2.1V$
							All others at V _{CC} or GND
I _{CCD}	Dynamic I _{CC} No Load			0.18	mA/MHz	Max	Outputs Open (Note 5)
	(Note 6)						$OEAB = \overline{OEBA} = GND$
							One bit toggling, 50% duty cycle

Note 4: Guaranteed but not tested.

Note 5: For 8 outputs toggling, I_{CCD} < 1.4 mA/MHz.

Note 6: Guaranteed, but not tested.

DC Electrical Characteristics

(SOIC package)

Symbol	Parameter	Parameter Min Typ Max Uni		Units	V _{CC}	Conditions	
Symbol	Farameter		Тур	Wax	Units	v CC	$\textbf{C}_{\textbf{L}} = \textbf{50}~\text{pF,}~\textbf{R}_{\textbf{L}} = \textbf{500}\Omega$
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}		0.6	8.0	V	5.0	T _A = 25°C (Note 7)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	-1.2	-0.9		V	5.0	T _A = 25°C (Note 7)
V _{OHV}	Minimum HIGH Level Dynamic Output Voltage	2.5	3.0		V	5.0	T _A = 25°C (Note 8)
V _{IHD}	Minimum HIGH Level Dynamic Input Voltage	2.2	1.8		V	5.0	T _A = 25°C (Note 9)
V _{ILD}	Maximum LOW Level Dynamic Input Voltage		0.8	0.4	V	5.0	T _A = 25°C (Note 9)

Note 7: Max number of outputs defined as (n). n – 1 data inputs are driven 0V to 3V. One output at LOW. Guaranteed, but not tested.

Note 8: Max number of outputs defined as (n). n - 1 data inputs are driven 0V to 3V. One output HIGH. Guaranteed, but not tested.

Note 9: Max number of data inputs (n) switching. n – 1 inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}). Guaranteed, but not tested.

AC Electrical Characteristics

(SOIC and SSOP Package)

Symbol	Parameter		$T_A = +25$ °C $V_{CC} = +5.0V$		$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $V_{CC} = 4.5\text{V} - 5.5\text{V}$ $C_L = 50 \text{ pF}$		Units
Oyiliboi	T arameter		$\text{C}_{\text{L}}=\text{50 pF}$				Onits
		Min	Тур	Max	Min	Max	
f _{max}	Max Clock Frequency	200			200		MHz
t _{PLH}	Propagation Delay	1.7	3.0	4.9	1.7	4.9	ns
t _{PHL}	Clock to Bus	1.7	3.4	4.9	1.7	4.9	
t _{PLH}	Propagation Delay	1.5	2.6	4.5	1.5	4.5	ns
t _{PHL}	Bus to Bus	1.5	3.0	4.5	1.5	4.5	
t _{PLH}	Propagation Delay	1.5	3.0	5.0	1.5	5.0	ns
t _{PHL}	SBA or SAB to A _n to B _n	1.5	3.4	5.0	1.5	5.0	
t _{PZH}	Enable Time	1.5	3.3	5.5	1.5	5.5	ns
t_{PZL}	OEBA or OEAB to A _n or B _n	1.5	3.7	5.5	1.5	5.5	
t _{PHZ}	Disable Time	1.5	3.7	6.0	1.5	6.0	ns
t_{PLZ}	OEBA or OEAB to A _n or B _n	1.5	3.3	6.0	1.5	6.0	

AC Operating Requirements

Symbol	Parameter	V _{CC} =	+25°C - +5.0V 50 pF	$T_A = -40^{\circ}$ 0 $V_{CC} = 4$ $C_L =$	Units	
		Min	Max	Min	Max	
t _S (H)	Setup Time, HIGH	1.5		1.5		ns
t _S (L)	or LOW Bus to Clock					
t _H (H)	Hold Time, HIGH	1.0		1.0		ns
t _H (L)	or LOW Bus to Clock					
t _W (H)	Pulse Width,	3.0		3.0		ns
$t_W(L)$	HIGH or LOW					

Extended AC Electrical Characteristics

(SOIC package):

Symbol	Parameter	V _{CC} = 4 C _L =	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $V_{CC} = 4.5\text{V} -5.5\text{V}$ $C_L = 50 \text{ pF}$ 8 Outputs Switching (Note 10)		$T_{A} = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $V_{CC} = 4.5\text{V} -5.5\text{V}$ $C_{L} = 250 \text{ pF}$ 1 Output Switching (Note 11)		$T_{A} = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $V_{CC} = 4.5\text{V} -5.5\text{V}$ $C_{L} = 250 \text{ pF}$ 8 Outputs Switching (Note 12)	
		Min	Max	Min	Max	Min	Max	
t _{PLH}	Propagation Delay	1.5	5.5	2.0	7.5	2.5	10.0	ns
t _{PHL}	Clock to Bus	1.5	5.5	2.0	7.5	2.5	10.0	
t _{PLH}	Propagation Delay	1.5	6.0	2.0	7.0	2.5	9.5	ns
t _{PHL}	Bus to Bus	1.5	6.0	2.0	7.0	2.5	9.5	
t _{PLH}	Propagation Delay	1.5	6.0	2.0	7.5	2.5	10.0	
t _{PHL}	SBA or SAB to A _n or B _n	1.5	6.0	2.0	7.5	2.5	10.0	ns
t _{PZH}	Output Enable Time	1.5	6.0	2.0	8.0	2.5	11.5	
t_{PZL}	OEBA or OEAB to A _n or B _n	1.5	6.0	2.0	8.0	2.5	11.5	ns
t _{PHZ}	Output Disable Time	1.5	6.0					
t _{PLZ}	OEBA or OEAB to A _n or B _n	1.5	6.0	(Note 13)		(Note 13)		ns

Note 10: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 11: This specification is guaranteed but not tested. The limits represent propagation delay with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load. This specification pertains to single output switching only.

Note 12: This specification is guaranteed but not tested. The limits represent propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.) with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

Note 13: The 3-STATE delay times are dominated by the RC network $(500\Omega, 250 \text{ pF})$ on the output and has been excluded from the datasheet.

Skew

(SOIC Package)

Symbol	Parameter	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $V_{CC} = 4.5\text{V} -5.5\text{V}$ $C_L = 50 \text{ pF}$ $8 \text{ Outputs Switching}$ (Note 16)	$T_{A} = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $V_{CC} = 4.5\text{V} -5.5\text{V}$ $C_{L} = 250 \text{ pF}$ $8 \text{ Outputs Switching}$ (Note 17)	Units
		Max	Max	
toshl	Pin to Pin Skew	1.3	2.5	ns
(Note 14)	HL Transitions			
toslh	Pin to Pin Skew	1.0	2.0	ns
(Note 14)	LH Transitions			
t _{PS}	Duty Cycle	2.0	4.0	ns
(Note 18)	LH-HL Skew			
t _{OST}	Pin to Pin Skew	2.0	4.0	ns
(Note 14)	LH/HL Transitions			
t _{PV}	Device to Device Skew	2.5	4.5	ns
(Note 15)	LH/HL Transitions			

Note 14: Skew is defined as the absolute value of the difference between the actual propagation delays for any two separate outputs of the same device. The specification applies to any outputs switching HIGH to LOW (toshL), LOW-to-HIGH (toshL), or any combination switching LOW-to-HIGH and/or HIGH-to-LOW (tosh). This specification is guaranteed but not tested.

Note 15: Propagation delay variation for a given set of conditions (i.e., temperature and V_{CC}) from device to device. This specification is guaranteed but not tested

Note 16: This specification is guaranteed but not tested. The limits apply to propagation delays for all paths described switching in phase (i.e., all LOW-to-HIGH, HIGH-to-LOW, etc.).

Note 17: This specification is guaranteed but not tested. The limits represent propagation delays with 250 pF load capacitors in place of the 50 pF load capacitors in the standard AC load.

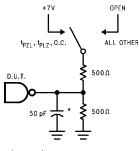
Note 18: This describes the difference between the delay of the LOW-to-HIGH and the HIGH-to-LOW transition on the same pin. It is measured across all the outputs (drivers) on the same chip, the worst (largest delta) number is the guaranteed specification. This specification is guaranteed but not tested.

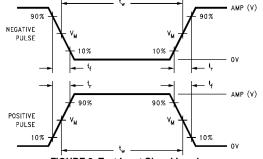
Capacitance

Symbol	Parameter	Тур	Units	Conditions (T _A = 25°C)
C _{IN}	Input Capacitance	5.0	pF	V _{CC} = 0V (non I/O pins)
C _{I/O} (Note 19)	I/O Capacitance	11.0	pF	$V_{CC} = 5.0 V (A_n, B_n)$

Note 19: C_{I/O} is measured at frequency, f = 1 MHz, per MIL-STD-883D, Method 3012.

AC Loading





*Includes jig and probe capacitance

FIGURE 2. Standard AC Test Load

FIGURE 3. Test Input Signal Levels

Input Pulse Requirements

Amplitude	Rep. Rate	t _W	t _r	t _f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 4. Test Input Signal Requirements

AC Waveforms

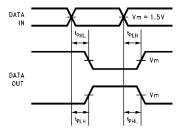


FIGURE 5. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

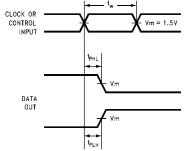


FIGURE 6. Propagation Delay, Pulse Width Waveforms

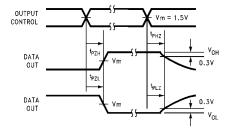
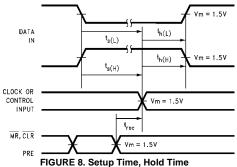
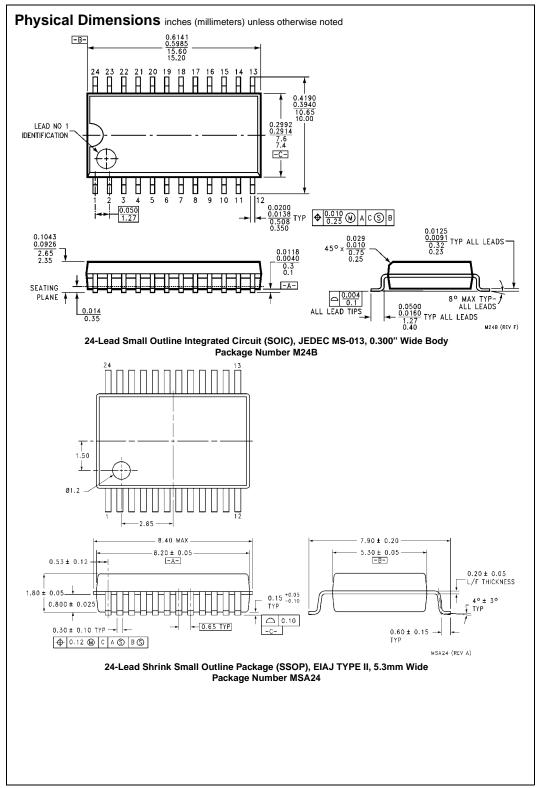
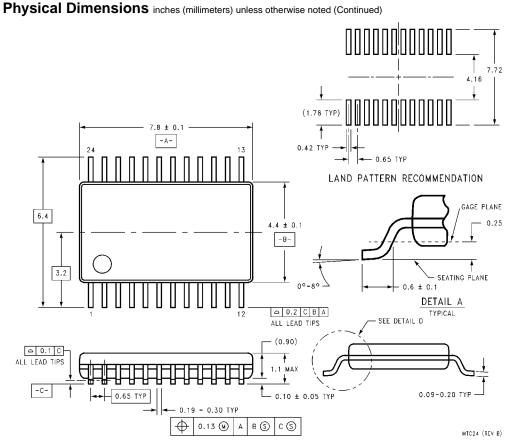


FIGURE 7. 3-STATE Output HIGH and LOW Enable and Disable Times



and Recovery Time Waveforms





24-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC24

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